UP04111/4113/4116

Silicon PNP epitaxial planar transistor

For switching/digital circuits

■ Features

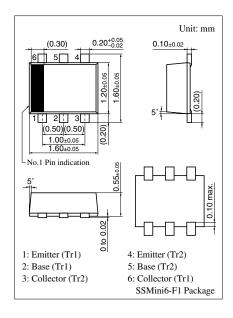
- Two elements incorporated into one package (Transistor with built-in resistor)
- Reduction of the mounting area and assembly cost by one half

■ Resistance by Part Number

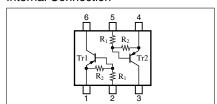
	Marking Symbol	(R_1)	(R_2)
• UP04111	9U	$10~\mathrm{k}\Omega$	$10 \text{ k}\Omega$
• UP04113	6S	$47~k\Omega$	$47~\mathrm{k}\Omega$
• UP04116	6U	$4.7~\mathrm{k}\Omega$	

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector to base voltage	V _{CBO}	-50	V	
Collector to emitter voltage	V _{CEO}	-50	V	
Collector current	I_{C}	-100	mA	
Total power dissipation	P _T	125	mW	
Junction temperature	T _j	125	°C	
Storage temperature	T _{stg}	-55 to +125	°C	



Internal Connection



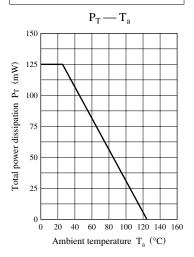
■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

Pa	rameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector cuto	ff current	I _{CBO}	$V_{CB} = -50 \text{ V}, I_E = 0$			- 0.1	μΑ
		I _{CEO}	$V_{CE} = -50 \text{ V}, I_B = 0$			- 0.5	
Emitter	UP04111	I _{EBO}	$V_{EB} = -6 \text{ V}, I_C = 0$			- 0.5	mA
cutoff current	UP04113					- 0.1	
	UP04116					- 0.01	
Collector to ba	se voltage	V _{CBO}	$I_{\rm C} = -10 \; \mu \text{A}, \; I_{\rm E} = 0$	-50			V
Collector to en	nitter voltage	V _{CEO}	$I_C = -2 \text{ mA}, I_B = 0$	-50			V
Forward current	UP04111	h _{FE}	$V_{CE} = -10 \text{ V}, I_{C} = -5 \text{ mA}$	35			
transfer ratio	UP04113			80			
	UP04116			160		460	
Collector to em	itter saturation voltage	V _{CE(sat)}	$I_C = -10 \text{ mA}, I_B = -0.3 \text{ mA}$			- 0.25	V

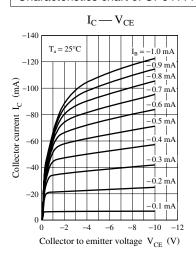
■ Electrical Characteristics (continued) $T_a = 25$ °C ± 3 °C

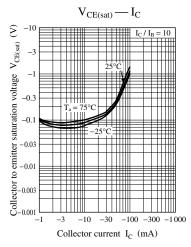
Pa	rameter	Symbol	Conditions	Min	Тур	Max	Unit
High-level out	put voltage	V _{OH}	$V_{CC} = -5 \text{ V}, V_B = -0.5 \text{ V}, R_L = 1 \text{ k}\Omega$	-4.9			V
Low-level outp	out voltage	V _{OL}	$V_{CC} = -5 \text{ V}, V_B = -2.5 \text{ V}, R_L = 1 \text{ k}\Omega$			- 0.2	V
	UP04113		$V_{CC} = -5 \text{ V}, V_B = -3.5 \text{ V}, R_L = 1 \text{ k}\Omega$				
Gain bandwidt	h product	f_T	$V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$		80		MHz
Input resistance	UP04116	R ₁		-30%	4.7	+30%	kΩ
	UP04111				10		
	UP04113				47		
Resistance ratio	UP04111/4113	R ₁ /R ₂		0.8	1.0	1.2	

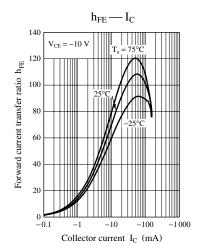
Common characteristics chart



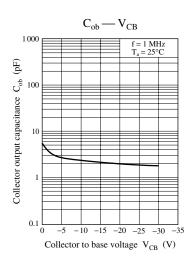
Characteristics chart of UP04111

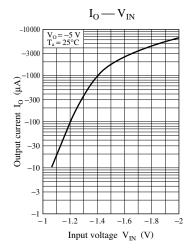


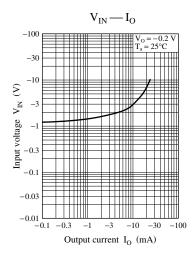




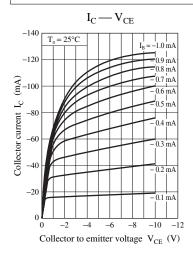
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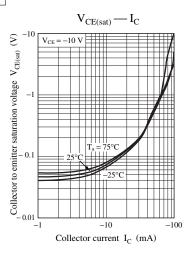


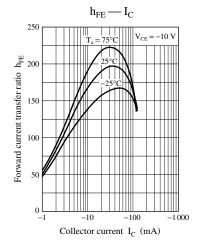


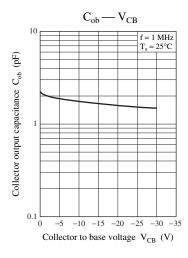


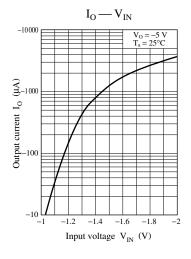
Characteristics chart of UP04113

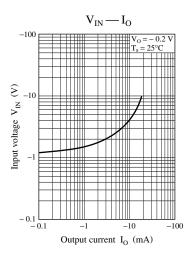






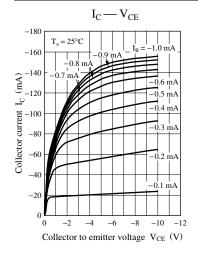


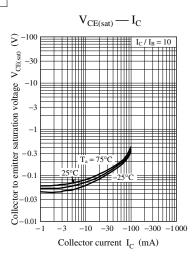


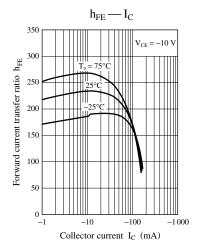


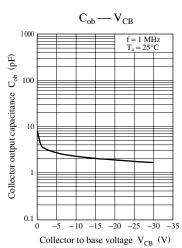
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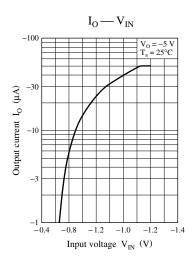
Characteristics chart of UP04116

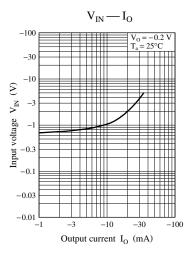












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